



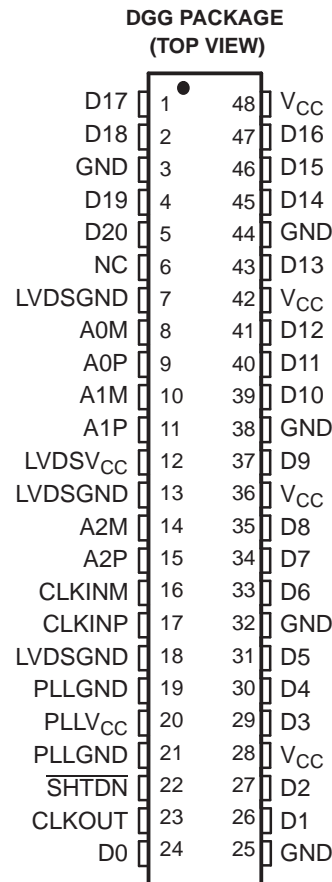
**THE DATASHEET OF
SN65LVDS96DGG**



LVDS SERDES RECEIVER

FEATURES

- 3:21 Data Channel Compression at up to 1.428 Gigabits/s Throughput
- Suited for Point-to-Point Subsystem Communication With Very Low EMI
- 3 Data Channels and Clock Low-Voltage Differential Channels in and 21 Data and Clock Low-Voltage TTL Channels Out
- Operates From a Single 3.3-V Supply and 250 mW (Typ)
- 5-V Tolerant $\overline{\text{SHTDN}}$ Input
- Rising Clock Edge Triggered Outputs
- Bus Pins Tolerate 4-kV HBM ESD
- Packaged in Thin Shrink Small-Outline Package With 20 Mil Terminal Pitch
- Consumes <1 mW When Disabled
- Wide Phase-Lock Input Frequency Range 20 MHz to 68 MHz
- No External Components Required for PLL
- Inputs Meet or Exceed the Requirements of ANSI EIA/TIA-644 Standard
- Industrial Temperature Qualified
 $T_A = -40^\circ\text{C}$ to 85°C
- Replacement for the DS90CR216



DESCRIPTION

The SN65LVDS96 LVDS serdes (serializer/deserializer) receiver contains three serial-in 7-bit parallel-out shift registers, a 7× clock synthesizer, and four low-voltage differential signaling (LVDS) line receivers in a single integrated circuit. These functions allow receipt of synchronous data from a compatible transmitter, such as the SN65LVDS95, over four balanced-pair conductors and expansion to 21 bits of single-ended LVTTTL synchronous data at a lower transfer rate.

When receiving, the high-speed LVDS data is received and loaded into registers at the rate of seven times the LVDS input clock (CLKIN). The data is then unloaded to a 21-bit wide LVTTTL parallel bus at the CLKIN rate. A phase-locked loop clock synthesizer circuit generates a 7× clock for internal clocking and an output clock for the expanded data. The SN65LVDS96 presents valid data on the rising edge of the output clock (CLKOUT).

The SN65LVDS96 requires only four line termination resistors for the differential inputs and little or no control. The data bus appears the same at the input to the transmitter and output of the receiver with data transmission transparent to the user(s). The only user intervention is the possible use of the shutdown/clear ($\overline{\text{SHTDN}}$) active-low input to inhibit the clock and shut off the LVDS receivers for lower power consumption. A low level on this signal clears all internal registers to a low level.

The SN65LVDS96 is characterized for operation over ambient air temperatures of -40°C to 85°C .

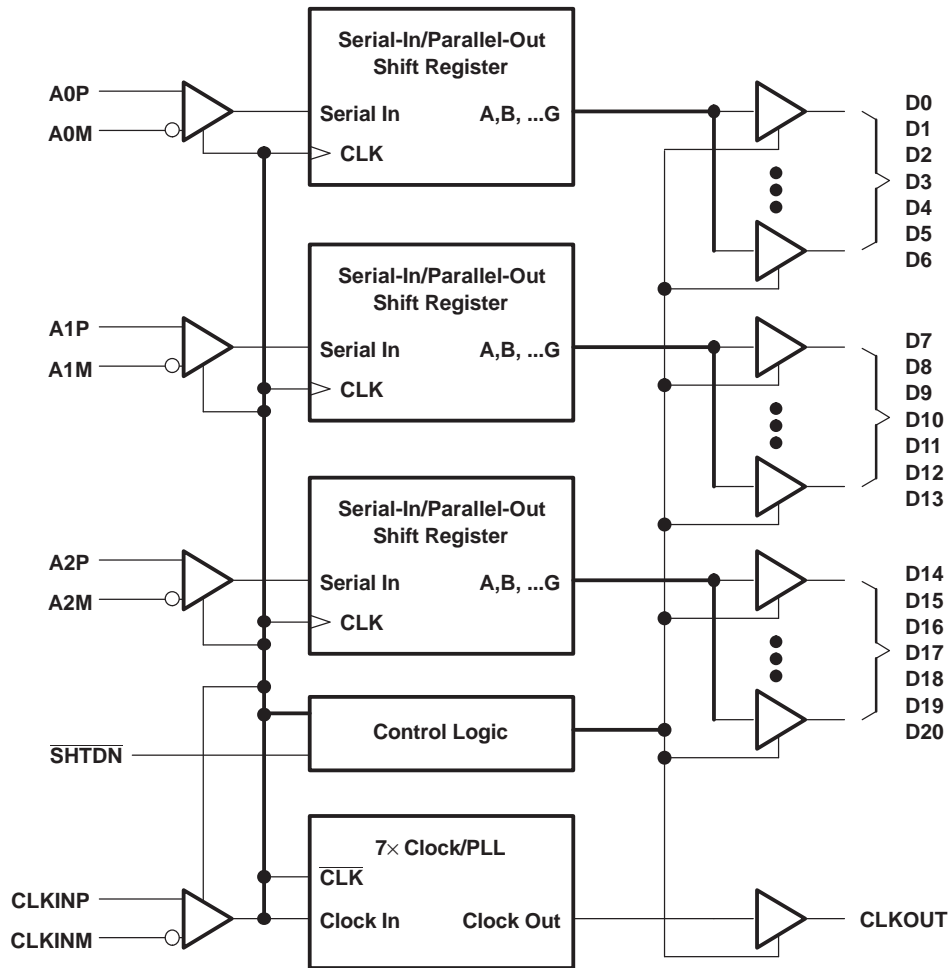


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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

FUNCTIONAL BLOCK DIAGRAM



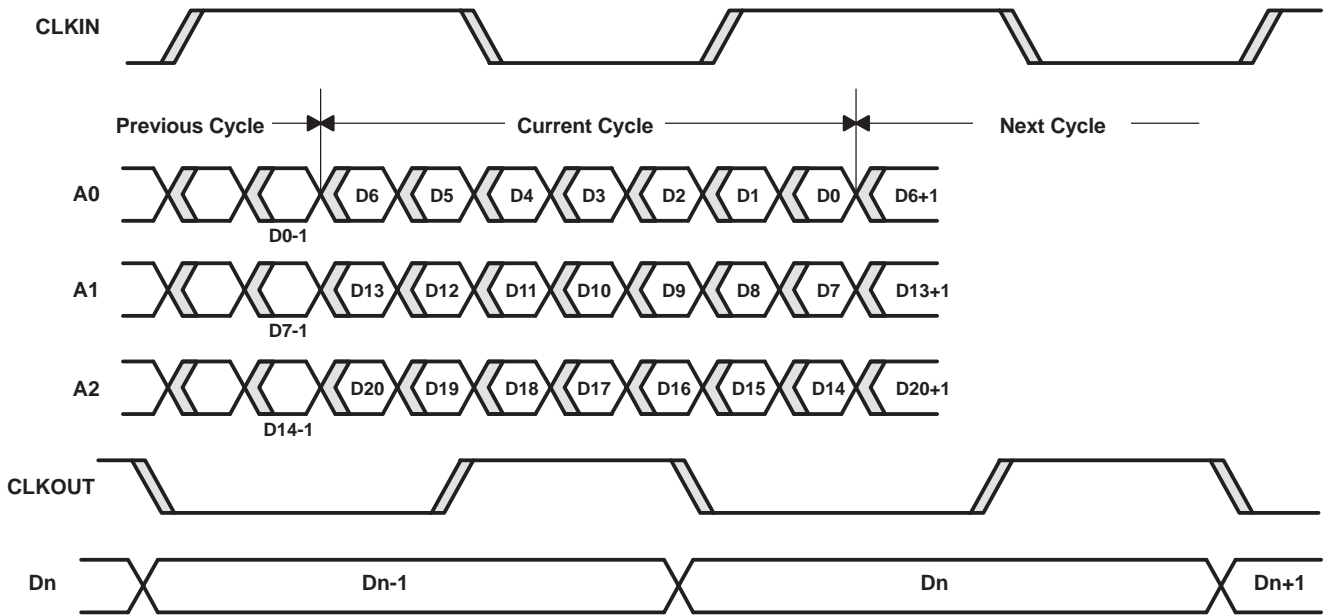
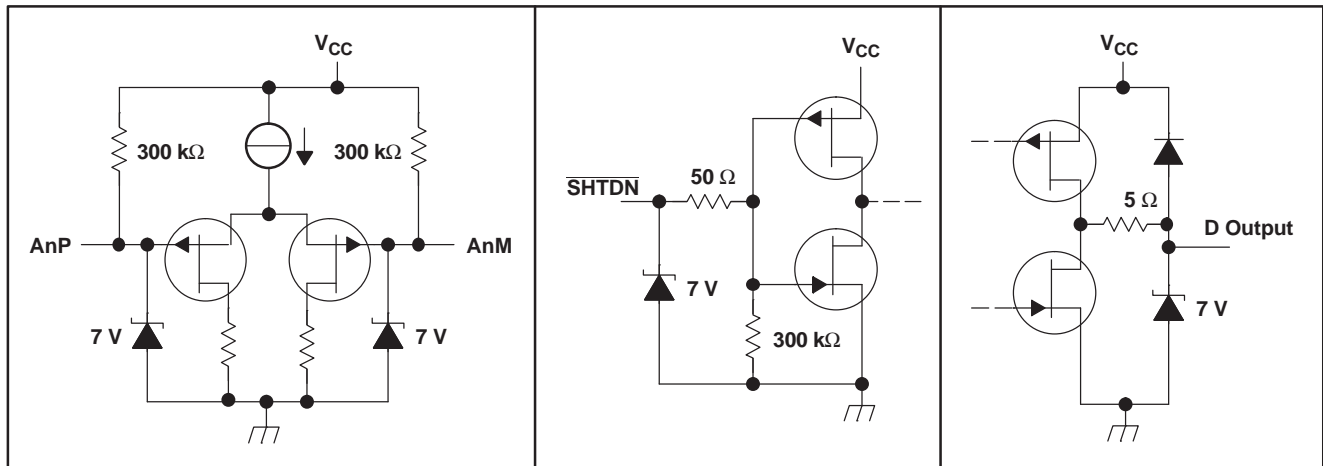


Figure 1. Typical 'LVDS96 Load and Shift Sequences

EQUIVALENT INPUT AND OUTPUT SCHEMATIC DIAGRAMS



ABSOLUTE MAXIMUM RATINGSover operating free-air temperature range (unless otherwise noted)⁽¹⁾

		UNIT
V _{CC}	Supply voltage range ⁽²⁾	–0.5 V to 4 V
Voltage range at any terminal (except SHTDN)		–0.5 V to V _{CC} + 0.5 V
Voltage range at SHTDN terminal		–0.5 V to 5.5 V
Electrostatic discharge ⁽³⁾	Bus pins (Class 3A)	4 KV
	Bus pins (Class 2B)	200 V
	All pins (Class 3A)	3 KV
	All pins (Class 2B)	200 V
Continuous total power dissipation		See Dissipation Rating Table
T _A	Operating free-air temperature range	–40°C to 85°C
T _{stg}	Storage temperature range	–65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds		260°C

- (1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values are with respect to the GND terminals unless otherwise noted.
- (3) This rating is measured using MIL-STD-883C Method, 3015.7.

DISSIPATION RATING TABLE

PACKAGE	T _A ≤ 25°C POWER RATING	DERATING FACTOR ⁽¹⁾ ABOVE T _A = 25°C	T _A = 70°C POWER RATING	T _A = 85°C POWER RATING
DGG	1316 mW	13.1 mW/°C	724 mW	526 mW

- (1) This is the inverse of the junction-to-ambient thermal resistance when board-mounted and with no air flow.

RECOMMENDED OPERATING CONDITIONS

		MIN	NOM	MAX	UNIT
V _{CC}	Supply voltage	3	3.3	3.6	V
V _{IH}	High-level input voltage	SHTDN			V
V _{IL}	Low-level input voltage	SHTDN		0.8	V
V _{ID}	Magnitude of differential input voltage	0.1		0.6	V
V _{IC}	Common-mode input voltage	$\frac{ V_{ID} }{2}$		$2.4 \times \frac{ V_{ID} }{2}$	V
				V _{CC} –0.8	
T _A	Operating free-air temperature	–40		85	°C

TIMING REQUIREMENTS

PARAMETERS		MIN	NOM	MAX	UNIT
t _c ⁽¹⁾	Input clock period	14.7	t _c	50	ns

- (1) t_c is defined as the mean duration of a minimum of 32,000 clock periods.

ELECTRICAL CHARACTERISTICS

over recommended operating conditions (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP ⁽¹⁾	MAX	UNIT
V _{IT+}	Positive-going differential Input voltage threshold				100	mV
V _{IT-}	Negative-going differential Input voltage threshold ⁽²⁾		-100			mV
V _{OH}	High-level output voltage	I _{OH} = -4 mA	2.4			V
V _{OL}	Low-level output voltage	I _{OH} = 4 mA			0.4	V
I _{CC}	Quiescent current (average)	Disabled, all inputs open			280	μA
		Enabled, AnP at 1 V and AnM at 1.4 V, t _c = 15.38 ns		60	82	mA
		Enabled, C _L = 8 pF, Worst-case pattern (see Figure 4), t _c = 15.38 ns		94		
I _{IH}	High-level input current (SHTDN)	V _{IH} = V _{CC}			±20	μA
I _{IL}	Low-level input current (SHTDN)	V _{IL} = 0 V			±20	μA
I _{IN}	Input current (A inputs)	0 V ≤ V _I ≤ 2.4 V			±20	μA
I _{OZ}	High-impedance output current	V _O = 0 V to V _{CC}			±10	μA

(1) All typical values are V_{CC} = 3.3 V, T_A = 25°C.

(2) The algebraic convention, in which the less-positive (more-negative) limit is designated minimum, is used in this data sheet for the negative-going input voltage threshold only.

SWITCHING CHARACTERISTICS

over recommended operating conditions (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT	
t _{su}	Data setup time, D0 through D20 to CLKOUT↑	C _L = 8 pF, See Figure 5	3.4	6		ns	
t _h	Data hold time, CLKOUT↑ to D0 through D20		4	6			
t _{RSKM}	Receiver input skew margin ⁽¹⁾ (see Figure 7)	t _c = 15.38 ns (±0.2%), Input clock jitter <50 ps ⁽²⁾	T _A = 0°C to 85°C		490	800	ps
			T _A = -40°C to 0°C		350		ps
t _d	Delay time, input clock to output clock (see Figure 7)	t _c = 15.38 ns (±0.2%)		3.7		ns	
Δt _{C(O)}	Change in output clock period from cycle to cycle ⁽³⁾	t _c = 15.38 + 0.75 sin(2π500E3t) ±0.05 ns, See Figure 7		±80		ps	
		t _c = 15.38 + 0.75 sin(2π3E6t) ±0.05 ns, See Figure 7		±300			
t _{en}	Enable time, SHTDN to phase lock	See Figure 8		1		ms	
t _{dis}	Disable time, SHTDN to Off state	See Figure 9		400		ns	
t _t	Output transition time (10% to 90% t _r or t _f)	C _L = 8 pF		3		ns	
t _w	Output clock pulse duration			0.43 t _c		ns	

(1) t_{RSKM} is the timing margin available to allocate to the transmitter and interconnection skews and clock jitter. The value of this parameter at clock periods other than 15.38 ns can be calculated from $\frac{t_c}{14} - 600$ ps.

(2) |Input clock jitter| is the magnitude of the change in the input clock period.

(3) Δt_{C(O)} is the change in the output clock period from one cycle to the next cycle observed over 15,000 cycles.

PARAMETER MEASUREMENT INFORMATION

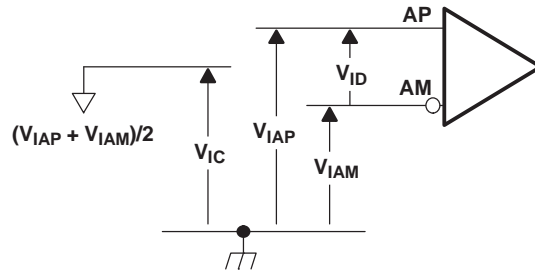


Figure 2. Voltage Definitions

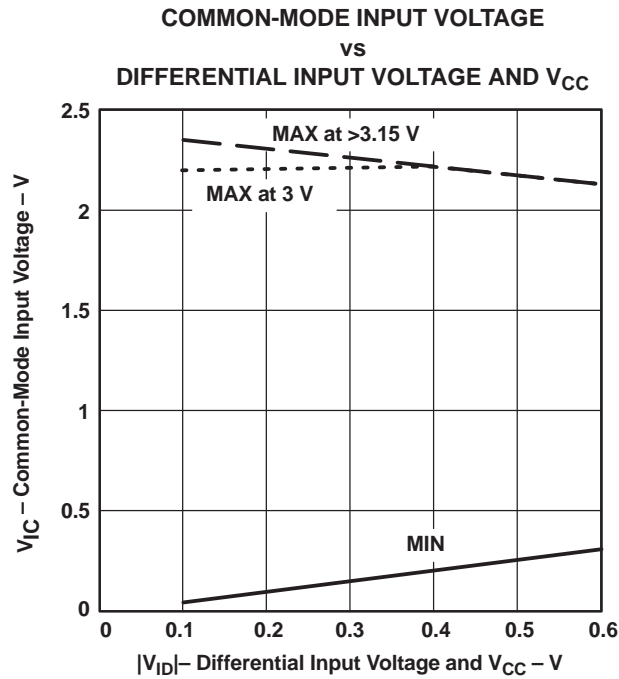
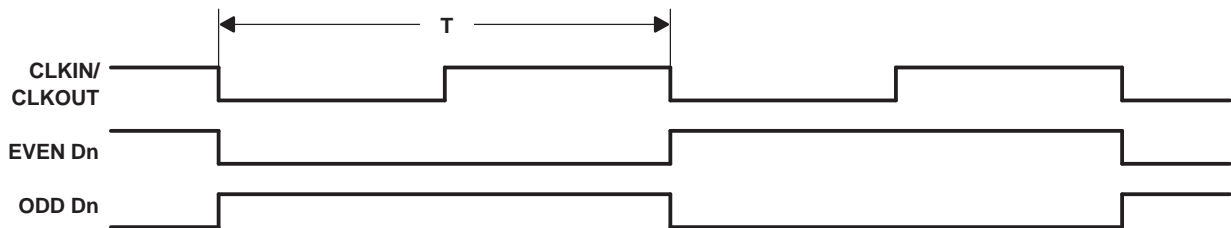


Figure 3. Maximum V_{IC} vs V_{ID} and V_{CC}



(1) The worst-case test pattern produces nearly the maximum switching frequency for all of the LV-TTL outputs.

Figure 4. Worst-Case⁽¹⁾ Test Pattern

PARAMETER MEASUREMENT INFORMATION (continued)

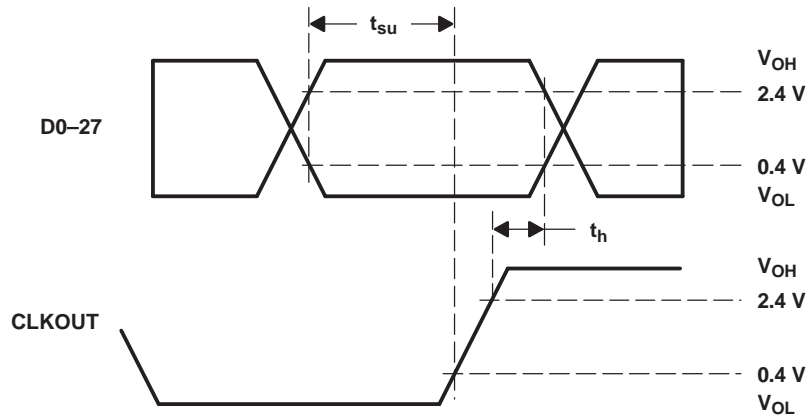
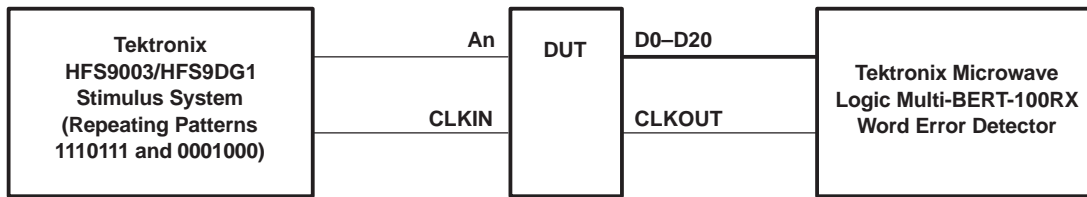


Figure 5. Setup and Hold-Time Measurements

PARAMETER MEASUREMENT INFORMATION (continued)



- NOTES: A. CLKIN is advanced or delayed with respect to data until errors are observed at the receiver outputs.
 B. The advance or delay is then reduced until there are no data errors observed.
 C. The magnitude of the advance or delay from step 2 is t_{RSKM} .

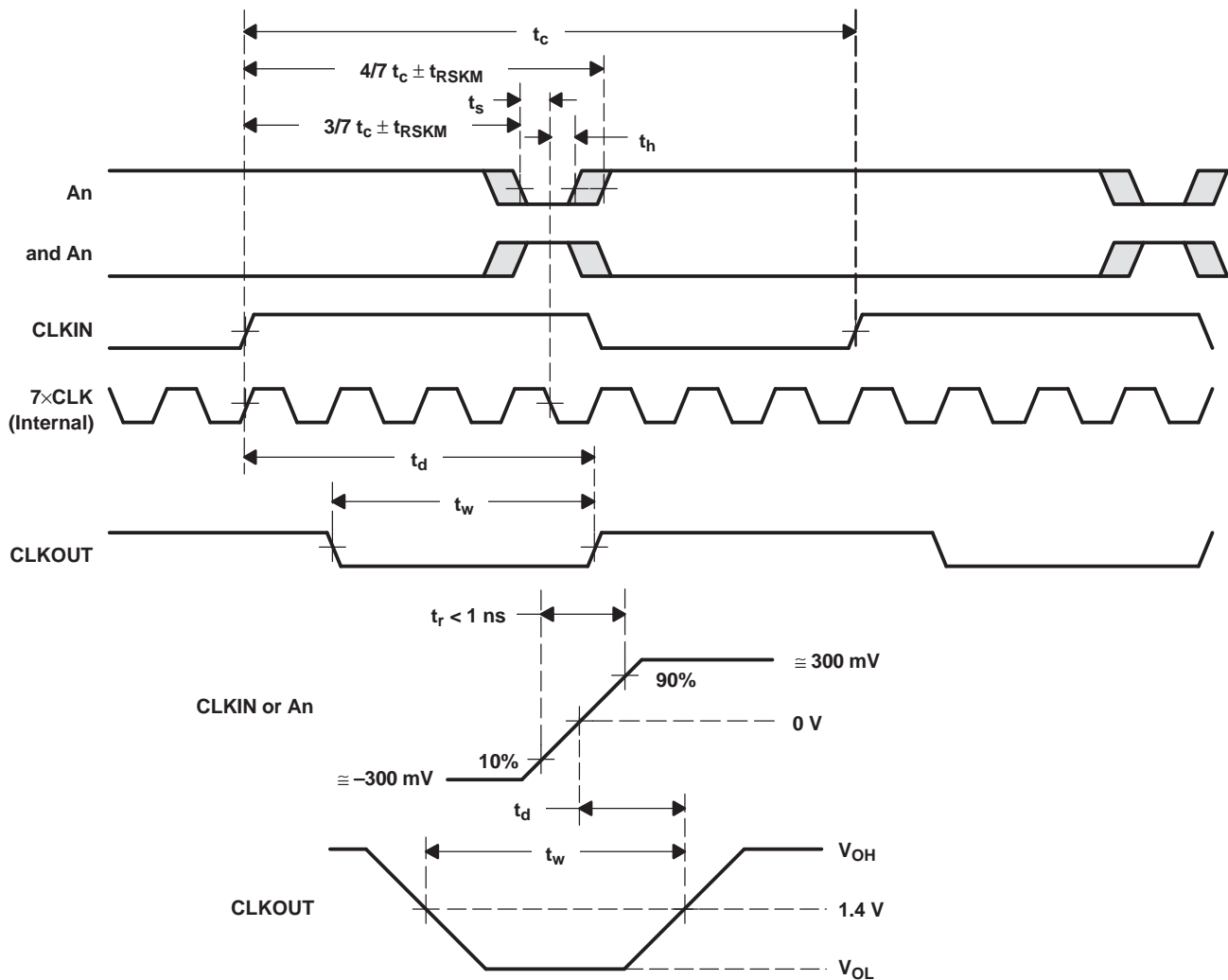


Figure 6. Receiver Input Skew Margin, Setup/Hold Time, and t_d Definitions

PARAMETER MEASUREMENT INFORMATION (continued)

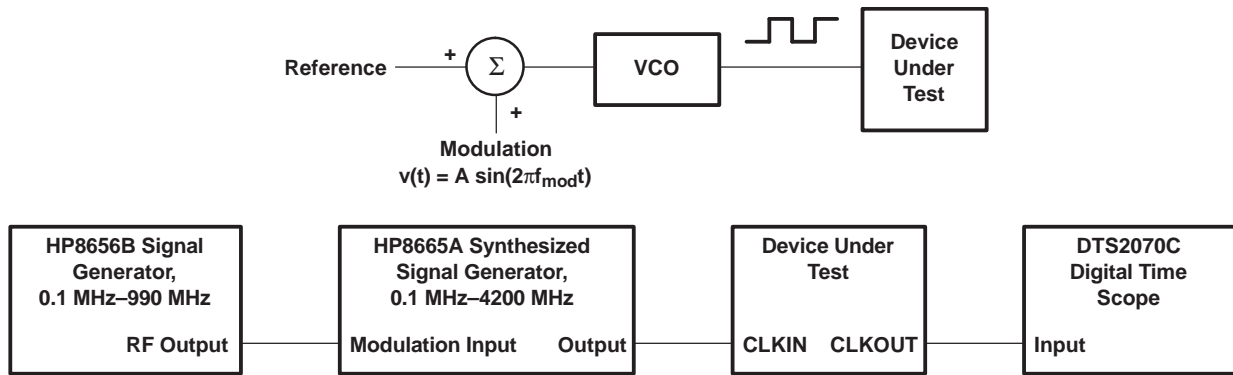


Figure 7. Output Clock Jitter Test Setup

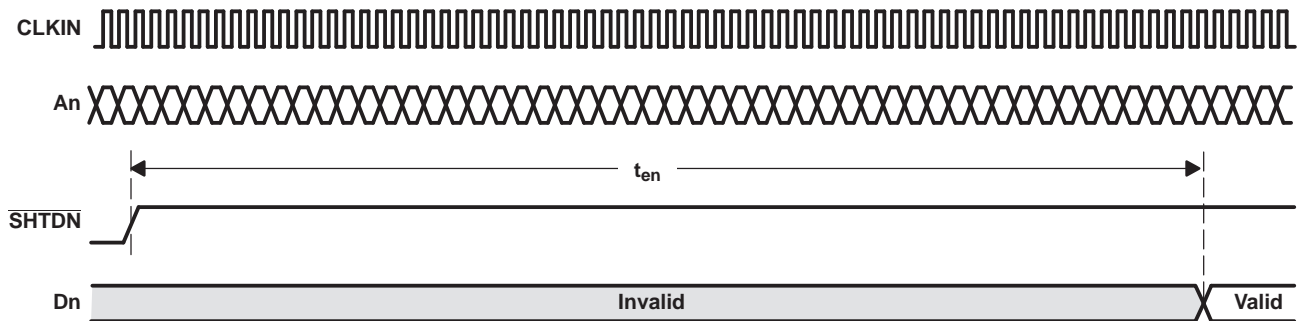


Figure 8. Enable Time Waveforms

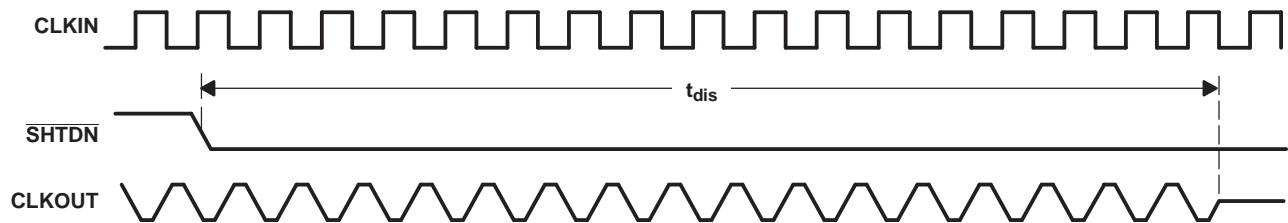


Figure 9. Disable Time Waveforms

TYPICAL CHARACTERISTICS
WORST-CASE SUPPLY CURRENT
vs
FREQUENCY

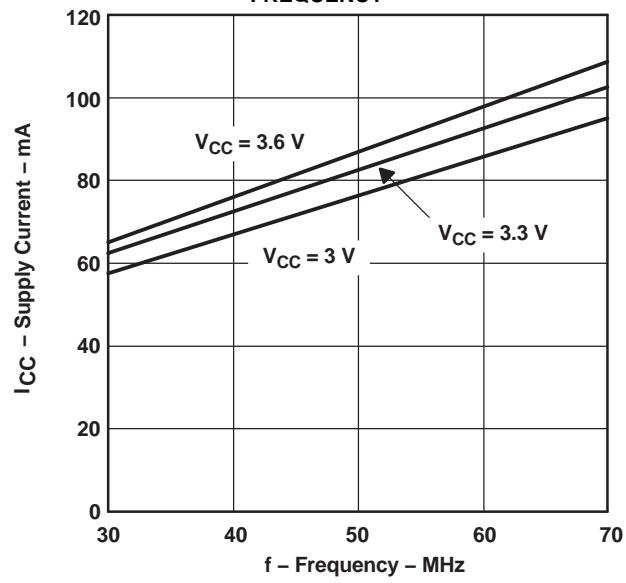


Figure 10.

APPLICATION INFORMATION

16-BIT BUS EXTENSION

In a 16-bit bus application (Figure 11), TTL data and clock coming from bus transceivers that interface the backplane bus arrive at the Tx parallel inputs of the LVDS serdes transmitter. The clock associated with the bus is also connected to the device. The on-chip PLL synchronizes this clock with the parallel data at the input. The data is then multiplexed into three different line drivers which perform the TTL to LVDS conversion. The clock is also converted to LVDS and presented to a separate driver. This synchronized LVDS data and clock at the receiver, which recovers the LVDS data and clock, performs a conversion back to TTL. Data is then demultiplexed into a parallel format. An on-chip PLL synchronizes the received clock with the parallel data, and then all are presented to the parallel output port of the receiver.

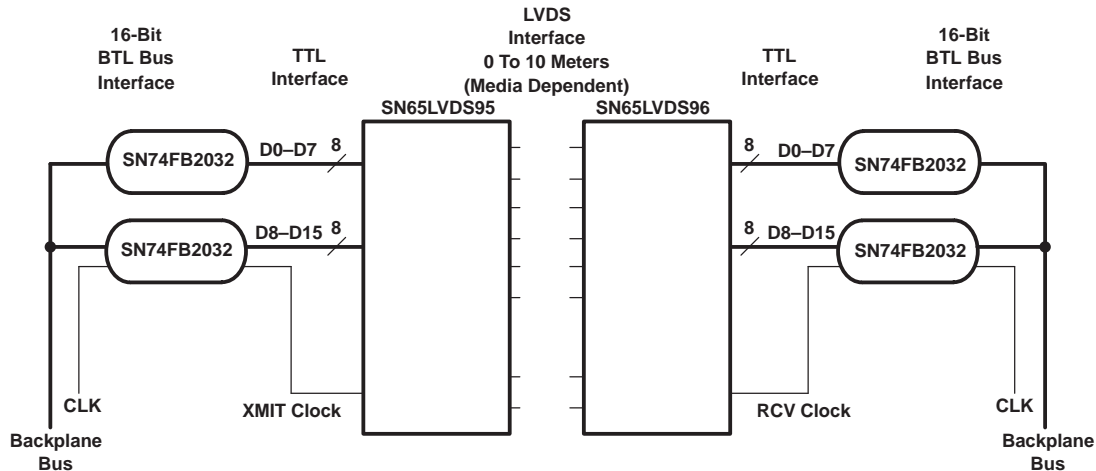


Figure 11. 16-Bit Bus Extension

16-BIT BUS EXTENSION WITH PARITY

In the previous application we did not have a checking bit that would provide assurance that the data crosses the link. If we add a parity bit to the previous example, we would have a diagram similar to the one in Figure 12. The device following the SN74FB2032 is a low cost parity generator. Each transmit-side transceiver/parity generator takes the LVTTTL data from the corresponding transceiver, performs a parity calculation over the byte, and then passes the bits with its calculated parity value on the parallel input of the LVDS serdes transmitter. Again, the on-chip PLL synchronizes this transmit clock with the eighteen parallel bits (16 data + 2 parity) at the input. The synchronized LVDS data/parity and clock arrive at the receiver.

The receiver performs the conversion from LVDS to LVTTTL and the transceiver/parity generator performs the parity calculations. These devices compare their corresponding input bytes with the value received on the parity bit. The transceiver/parity generator will assert its parity error output if a mismatch is detected.

APPLICATION INFORMATION (continued)

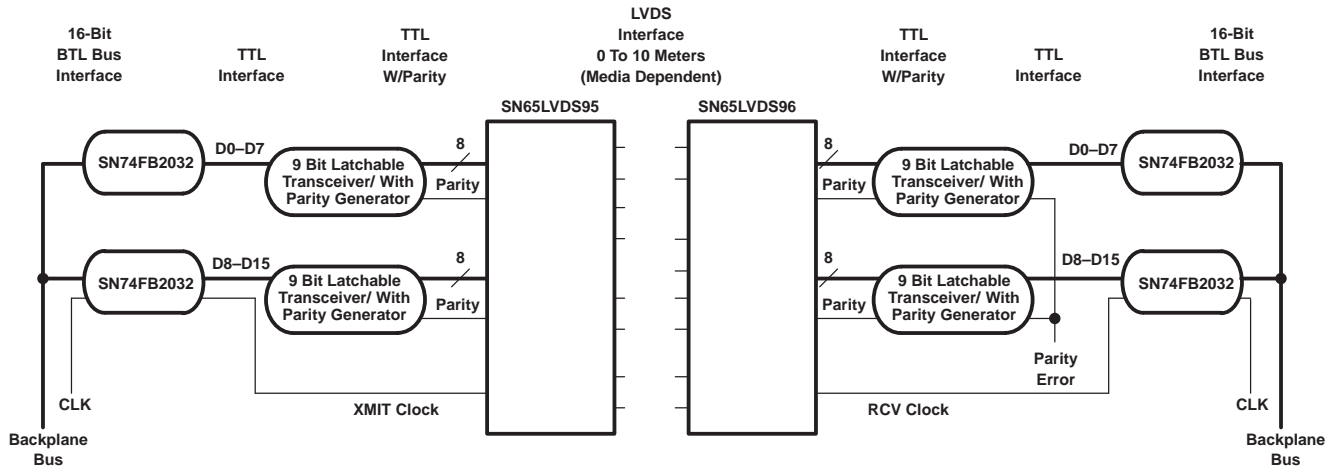


Figure 12. 16-Bit Bus Extension With Parity

LOW COST VIRTUAL BACKPLANE TRANSCEIVER

Figure 13 represents LVDS serdes in an application as a virtual backplane transceiver (VBT). The concept of a VBT can be achieved by implementing individual LVDS serdes chipsets in both directions of subsystem serialized links.

Depending on the application, the designer will face varying choices when implementing a VBT. In addition to the devices shown in Figure 13, functions such as parity and delay lines for control signals could be included. Using additional circuitry, half-duplex or full-duplex operation can be achieved by configuring the clock and control lines properly.

The designer may choose to implement an independent clock oscillator at each end of the link and then use a PLL to synchronize LVDS serdes's parallel I/O to the backplane bus. Resynchronizing FIFOs may also be required.

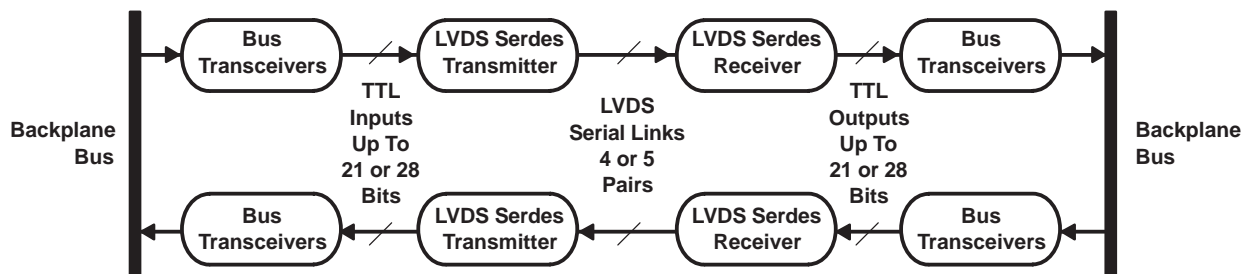


Figure 13. Virtual Backplane Transceiver

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
SN65LVDS96DGG	ACTIVE	TSSOP	DGG	48	40	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR		SN65LVDS96	Samples
SN65LVDS96DGGG4	ACTIVE	TSSOP	DGG	48	40	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR		SN65LVDS96	Samples
SN65LVDS96DGGR	ACTIVE	TSSOP	DGG	48	2000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	SN65LVDS96	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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TAPE AND REEL INFORMATION

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN65LVDS96DGGR	TSSOP	DGG	48	2000	330.0	24.4	8.6	13.0	1.8	12.0	24.0	Q1

TAPE AND REEL BOX DIMENSIONS

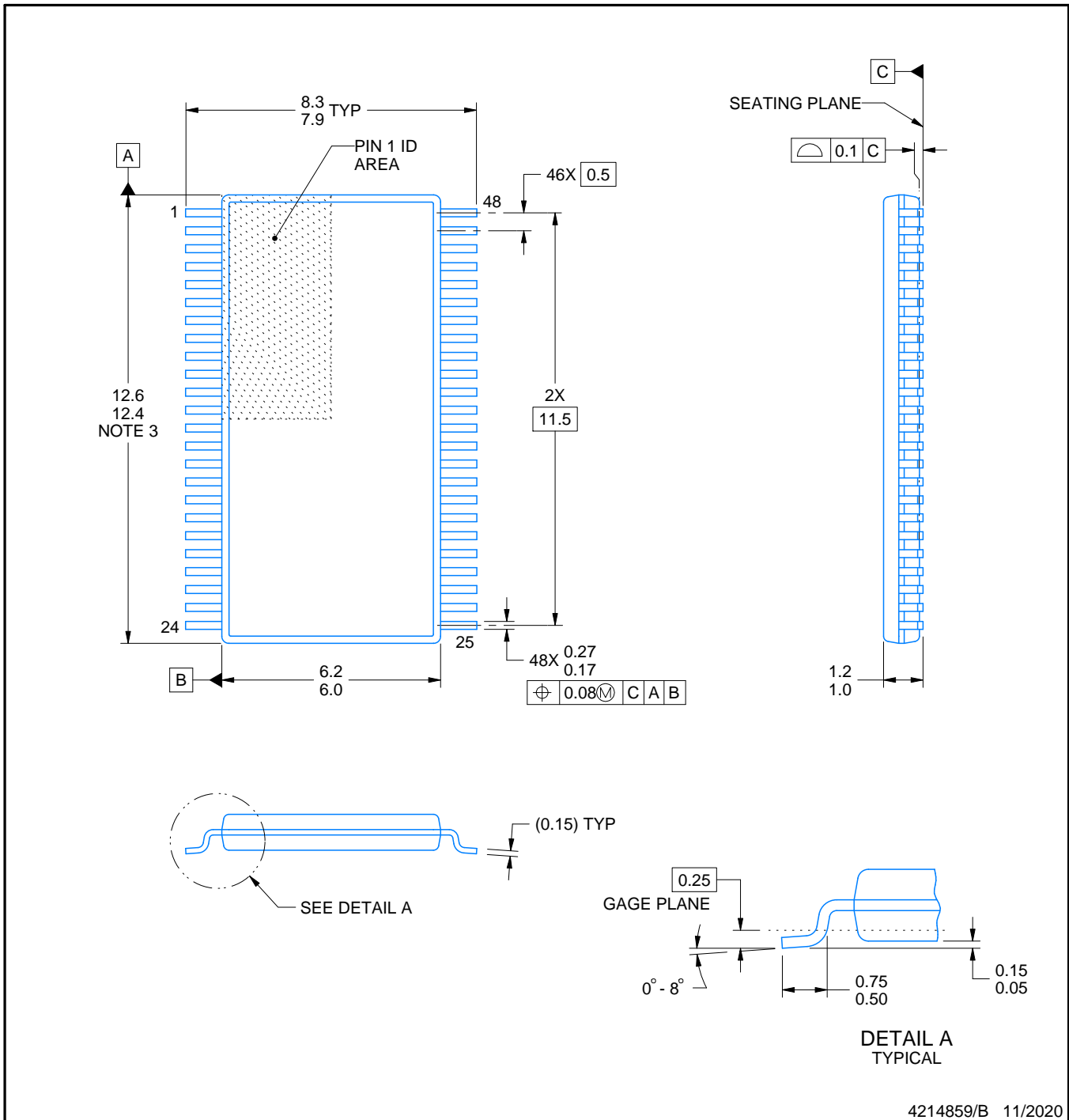
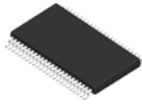

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN65LVDS96DGGR	TSSOP	DGG	48	2000	350.0	350.0	43.0

TUBE


*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
SN65LVDS96DGG	DGG	TSSOP	48	40	530	11.89	3600	4.9
SN65LVDS96DGGG4	DGG	TSSOP	48	40	530	11.89	3600	4.9



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NOTES:

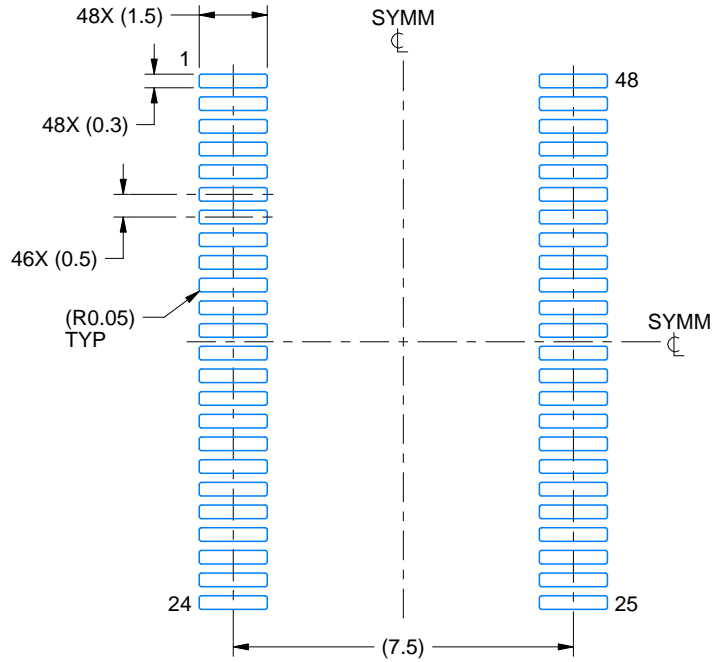
- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- This drawing is subject to change without notice.
- This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
- Reference JEDEC registration MO-153.

EXAMPLE BOARD LAYOUT

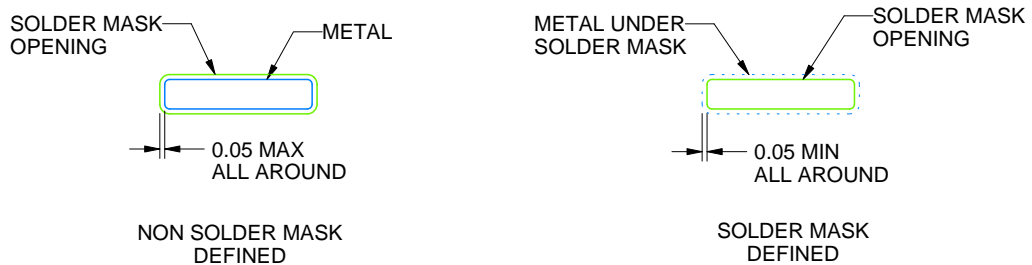
DGG0048A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
SCALE:6X



SOLDER MASK DETAILS

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NOTES: (continued)

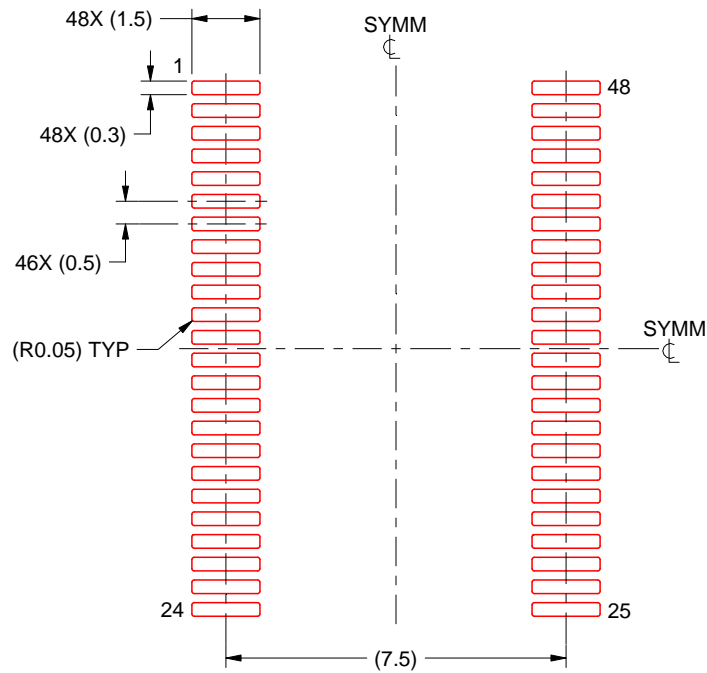
- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DGG0048A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:6X

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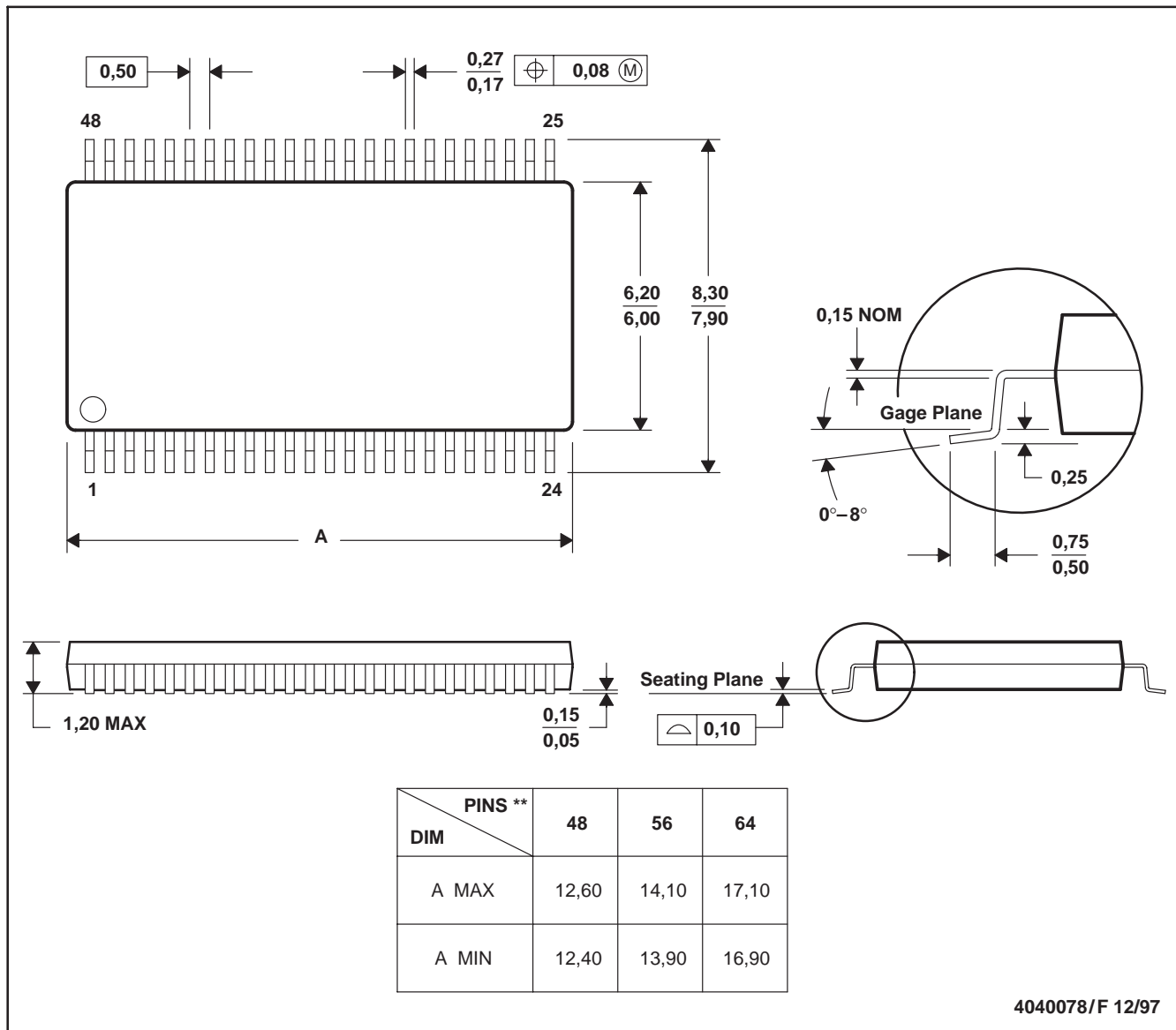
NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.

DGG (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

48 PINS SHOWN



- NOTES: A. All linear dimensions are in millimeters.
 B. This drawing is subject to change without notice.
 C. Body dimensions do not include mold protrusion not to exceed 0,15.
 D. Falls within JEDEC MO-153

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